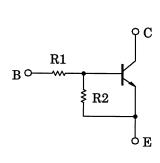
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

RN1421,RN1422,RN1423,RN1424 RN1425,RN1426,RN1427

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

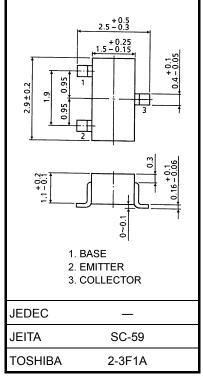
- High current type (IC (max) = 800mA)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Low VCE (sat)
- Complementary to RN2401~RN2406

Equivalent Circuit and Bias Resister Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN1421	1	1
RN1422	2.2	2.2
RN1423	4.7	4.7
RN1424	10	10
RN1425	0.47	10
RN1426	1	10
RN1427	2.2	10

Unit: mm



Weight: 0.012 g (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characterist	Symbol	Rating	Unit		
Collector-base voltage	RN1421~1427	V _{CBO}	50	V	
Collector-emitter voltage	1(111421*1421	V _{CEO}	50	V	
	RN1421~1424		10	V	
Emitter-base voltage	RN1425, 1426	V_{EBO}	5		
	RN1427		6		
Collector current		IC	800	mA	
Collector power dissipation	RN1421~1427	PC	200	mW	
Junction temperature	KIN1421**1421	Tj	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

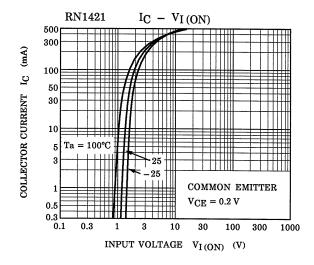
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

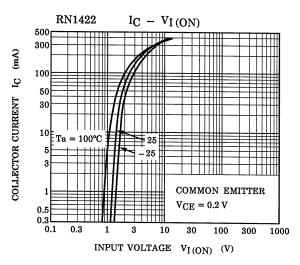
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

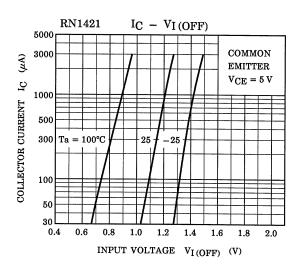


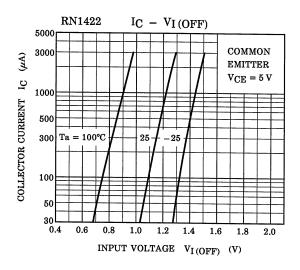
Electrical Characteristics (Ta = 25°C)

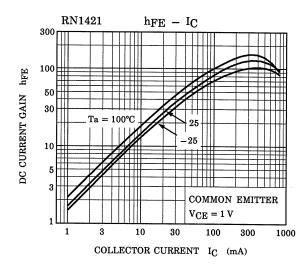
Character	istic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN1421~1427	I _{CBO}		V _{CB} = 50V, I _E = 0	_	_	100	nΛ
	KIN 142 1 1421	I _{CEO}		V _{CE} = 50V, I _B = 0	_	_	500	nA
	RN1421	I _{EBO}	_	V _{EB} = 10V, I _C = 0	3.85	_	7.14	mA
	RN1422				1.75	_	3.25	
	RN1423				0.82	_	1.52	
Emitter cut-off current	RN1424				0.38	_	0.71	
	RN1425			V _{EB} = 5V, I _C = 0	0.365	_	0.682	
	RN1426				0.35	_	0.65	
	RN1427			V _{EB} = 6V, I _C = 0	0.378	_	0.703	
	RN1421				60	_	_	
	RN1422				65	_	_	
	RN1423				70	_	_	
DC current gain	RN1424	hFE		V _{CE} = 1V, I _C = 100mA	90	_	_	_
	RN1425	.,, L			90	_	_	
	RN1426				90	_	_	
	RN1427				90	_	_	
Collector-emitter	RN1421~1427	Vo= ()		I _C = 50mA, I _B = 2mA			0.25	V
saturation voltage	KN 142 1~ 1421	V _{CE} (sat)		I _C = 50mA, I _B = 1mA		_	0.25	V
	RN1421			V _{CE} = 0.2V, I _C = 100mA	1.0	_	3.5	V
	RN1422				1.4	_	4.5	
	RN1423				2.0	_	6.5	
Input voltage (ON)	RN1424	V _I (ON) —	_		3.0	_	12.0	
ļ	RN1425				0.6	_	2.0	
	RN1426				0.7	_	2.5	
	RN1427				1.0	_	3.0	
	RN1421~1424		r) —	V _{CE} = 5V, I _C = 0.1mA	0.8	_	1.3	
Input voltage (OFF)	RN1425, 1426	V _{I (OFF)}			0.4	_	0.8	V
	RN1427				0.5		1.0	
Transition frequency	RN1421~1427	f _T	_	V_{CE} = 5V, I_{C} = 20mA	_	300	_	MHz
Collector Output capacitance	RN1421~1427	C _{ob}	_	$V_{CB} = 10V, I_{E} = 0,$ f = 1MH _z	_	7	_	pF
	RN1421				0.7	1.0	1.3	
	RN1422				1.54	2.2	2.86	
Input resistor	RN1423		R1 — —		3.29	4.7	6.11	
	RN1424	R1 –			7	10	13	kΩ
	RN1425			0.329	0.47	0.61		
	RN1426				0.7	1.0	1.3	
	RN1427				1.54	2.2	2.86	
Resistor ratio	RN1421~1424			_	0.9	1.0	1.1	
	RN1425	R1/R2			0.0423	0.047	0.0517	_
	RN1426	r i/rZ	_		0.09	0.1	0.11	
	RN1427				0.2	0.22	0.24	

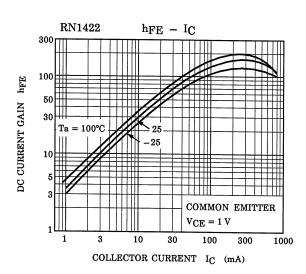




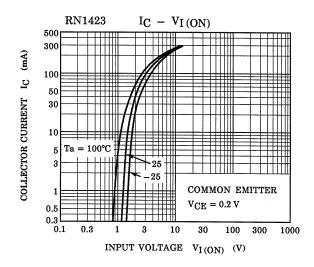


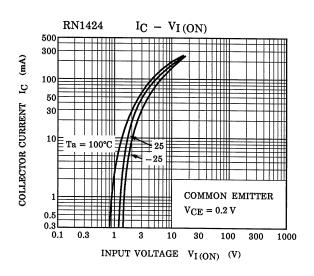


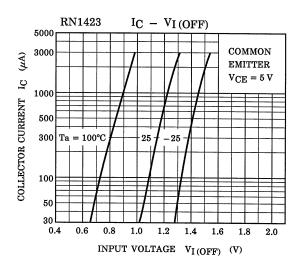


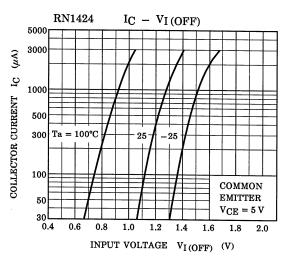


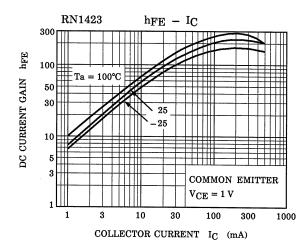
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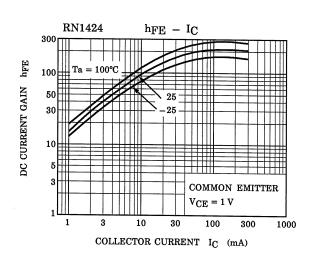


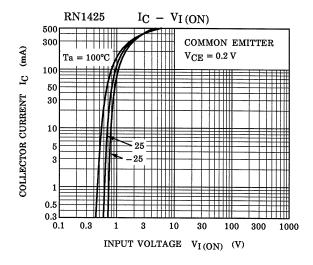


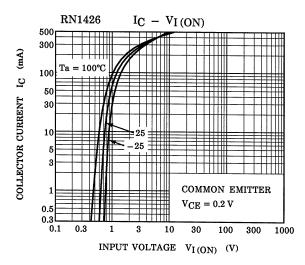


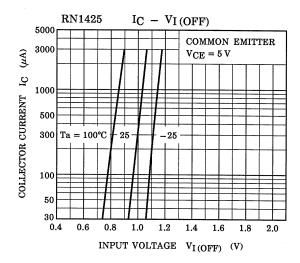


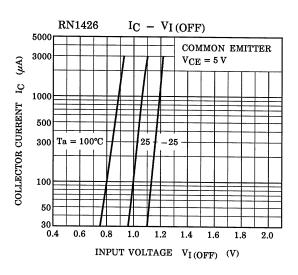


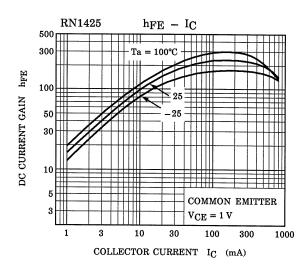


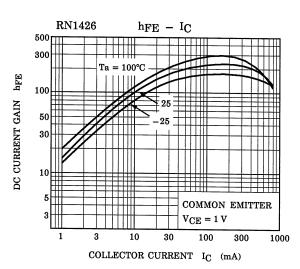


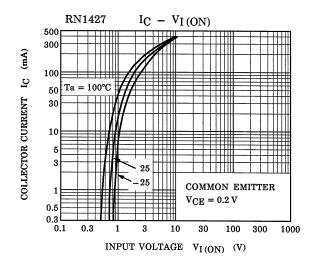


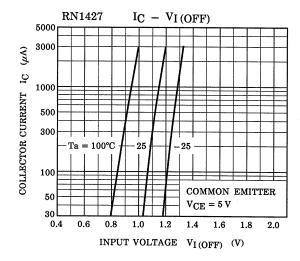


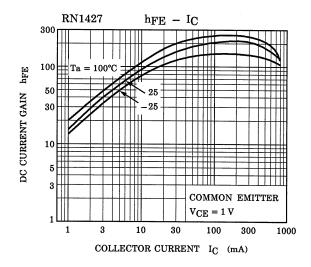












Type Name	Marking	
RN1421	Type Name Q A	
RN1422	Type Name Q B	
RN1423	Type Name Q C	
RN1424	Type Name Q D	
RN1425	Type Name Q E	
RN1426	Type Name Q F	
RN1427	Type Name Q G	

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RESTRICTIONS ON PRODUCT USE

20070701-EN GENERAL

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